

HM6708A Series

Preliminary

65536-Word × 4-Bit High Speed Static RAM

T-46-23-10

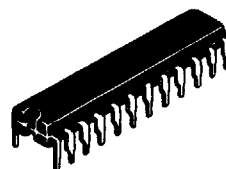
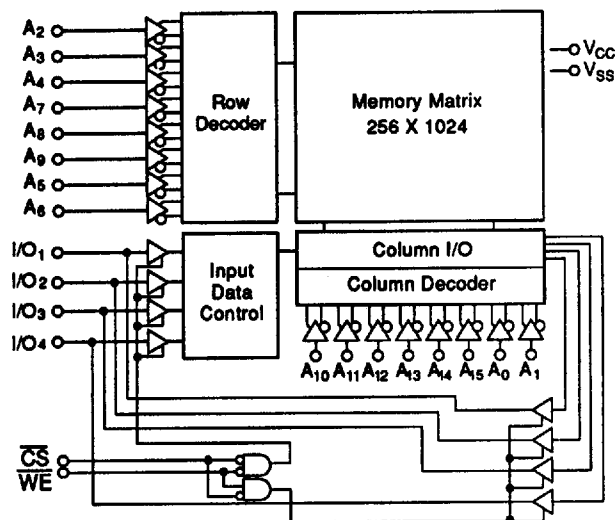
■ FEATURES

- 65536-words × 4 bit organization
- Fully TTL compatible input and output
- 1.0μ Hi-BiCMOS process
- +5V single supply
- Completely static memory
No clock or timing strobe required
- Low power dissipation
Operating: 450mW (typ.)
- Super fast
Access time: 15/20/25 ns (max.)

■ ORDERING INFORMATION

Type No.	Access Time	Package
HM6708AP-15	15ns	300 mil 24 pin Plastic DIP (DP-24NC)
HM6708AP-20	20ns	
HM6708AP-25	25ns	
HM6708AJP-15	15ns	300 mil 24 pin Plastic SOJ (CP-24D)
HM6708AJP-20	20ns	
HM6708AJP-25	25ns	

■ BLOCK DIAGRAM

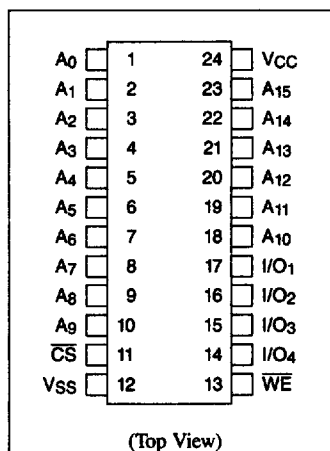


(DP-24NC)



(CP-24D)

■ PIN ARRANGEMENT



■ PIN DESCRIPTION

Pin Name	Function
A ₀ -A ₁₅	Address Input
I/O ₁ -I/O ₄	Data Input/Output
WE	Write Enable
CS	Chip Select
V _{SS}	Ground
V _{CC}	Power Supply



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• Write Cycle

Item	Symbol	HM6708A-15		HM6708A-20		HM6708A-25		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
Write Cycle Time	$t_{WC}^{1)}$	15	—	20	—	25	—	ns
Chip Selection to End of Write	t_{CW}	10	—	15	—	20	—	ns
Address Valid to End of Write	t_{AW}	10	—	15	—	20	—	ns
Address Setup Time	t_{AS}	0	—	0	—	0	—	ns
Write Pulse Width	t_{WP}	10	—	15	—	20	—	ns
Write Recovery Time	t_{WR}	0	—	0	—	0	—	ns
Data Valid to End of Write	t_{DW}	8	—	10	—	12	—	ns
Data Hold Time	t_{DH}	0	—	0	—	0	—	ns
Write Enable to Output in High Z	$t_{WZ}^{2), 3)}$	0	6	0	8	0	10	ns
Output Active from End of Write	$t_{OW}^{2), 3)}$	0	—	0	—	0	—	ns

NOTES: 1. All write cycle timings are referenced from the last valid address to the first transitioning address.

2. This parameter is sampled and not 100% tested.

3. Transition is measured ± 200 mV from steady state voltage with specified loading in Load(B).

■ CAPACITANCE ($T_a = 25^\circ\text{C}$, $f = 1\text{MHz}$)

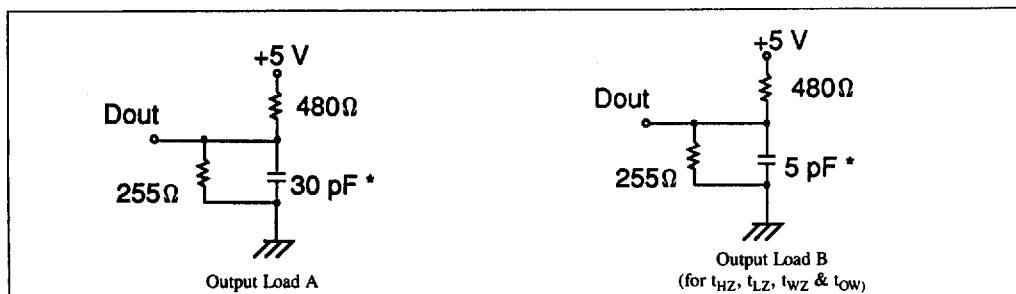
Item	Symbol	Max.	Unit	Test Condition
Input Capacitance	$C_{IN}^{1)}$	6	pF	$V_{IN} = 0\text{ V}$
Output Capacitance	$C_{IO}^{1)}$	10	pF	$V_{IO} = 0\text{ V}$

NOTES: 1. This parameter is sampled and not 100% tested.

■ AC TEST CONDITIONS

- Input pulse levels: V_{SS} to 3.0 V
- Input timing reference levels: 1.5 V
- Output Load: See figure

- Input rise and fall times: 4ns
- Output reference levels: 1.5 V



*Including scope and jig capacitance.



■ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Rating	Unit
Terminal Voltage to V_{SS} Pin	V_T	-0.5 to +7.0	V
Power Dissipation	P_T	1.0	W
Operating Temperature Range	T_{opr}	0 to +70	°C
Storage Temperature Range (with bias)	$T_{stg(bias)}$	-10 to +85	°C
Storage Temperature Range	T_{stg}	-55 to +125	°C

■ RECOMMENDED DC OPERATING CONDITIONS (0°C ≤ T_a ≤ 70°C)

Item	Symbol	Min.	Typ.	Max.	Unit
Supply Voltage	V_{CC}	4.5	5.0	5.5	V
	V_{SS}	0.0	0.0	0.0	V
Input High (Logic 1) Voltage	V_{IH}	2.2	—	$V_{CC} + 0.5$	V
Input Low (Logic 0) Voltage	V_{IL}	-3.0*	—	0.8	V

*Pulse width 20ns, DC: -0.5V

■ FUNCTION TABLE

$\overline{CS}$	$\overline{WE}$	Mode	V_{CC} Current	I/O Pin	Ref. Cycle
H	X	Not Selected	I_{SB}, I_{SB1}	High Z	—
L	H	Read	I_{CC}, I_{CC1}	Data Out	Read Cycle (1) (2)
L	L	Write	I_{CC}, I_{CC1}	Data In	Write Cycle (1) (2)

■ DC AND OPERATING CHARACTERISTICS ($V_{CC}=5.0\text{ V} \pm 10\%$, $T_a=0$ to +70°C)

Item	Symbol	Test Conditions	HM6708A-15			HM6708A-20/25			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Leakage Current	$ I_{LI} $	$V_{CC}=5.5\text{ V}$, $V_{IN}=0\text{ V}$ to V_{CC}	—	—	2	—	—	2	μA
Output Leakage Current	$ I_{LO} $	$\overline{CS}=V_{IH}$, $V_{I/O}=0\text{ V}$ to V_{CC}	—	—	10	—	—	10	μA
Operating Power Supply Current	I_{CC}	$\overline{CS}=V_{IL}$, $I_{I/O}=0\text{ mA}$	—	—	100	—	—	100	mA
Average Operating Current	I_{CC1}	min. cycle, Duty: 100% $I_{I/O}=0\text{ mA}$	—	—	140	—	—	120	mA
Standby Power Supply Current	I_{SB}	$\overline{CS}=V_{IH}$, $V_{IN}=V_{IH}$ or V_{IL}	—	—	30	—	—	30	mA
	I_{SB1}	$\overline{CS} \geq V_{CC}-0.2\text{ V}$ $V_{IN} \leq 0.2\text{ V}$ or $V_{IN} \geq V_{CC}-0.2\text{ V}$	—	—	10	—	—	10	mA
Output Low Voltage	V_{OL}	$I_{OL}=8\text{ mA}$	—	—	0.4	—	—	0.4	V
Output High Voltage	V_{OH}	$I_{OH}=-4\text{ mA}$	2.4	—	—	2.4	—	—	V

■ AC CHARACTERISTICS ($V_{CC}=5\text{ V} \pm 10\%$, $T_a=0$ to +70°C, unless otherwise noted.)

• Read Cycle

Item	Symbol	HM6708A-15		HM6708A-20		HM6708A-25		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
Read Cycle Time	t_{RC}	15	—	20	—	25	—	ns
Address Access Time	t_{AA}	—	15	—	20	—	25	ns
Chip Select Access Time	t_{ACS}	—	15	—	20	—	25	ns
Output Hold from Address Change	t_{OH}	4	—	5	—	5	—	ns
Chip Selection to Output in Low Z	$t_{LZ}^{(1), (2)}$	4	—	5	—	5	—	ns
Chip Deselection to Output in High Z	$t_{HZ}^{(1), (2)}$	0	6	0	8	5	10	ns

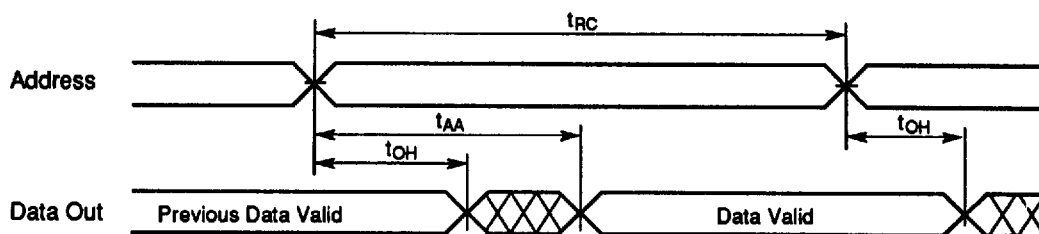
NOTES: 1. This parameter is sampled and not 100% tested.

2. Transition is measured $\pm 200\text{ mV}$ from steady state voltage with specified loading in Load(B).

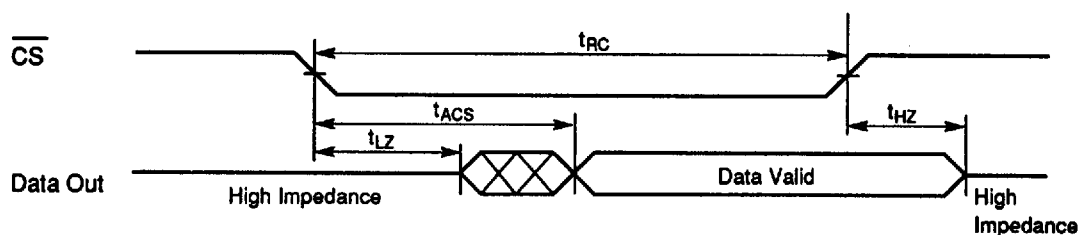
■ TIMING WAVEFORM

• Read Cycle (1) (1) (2)

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• Read Cycle (2) (1) (3)

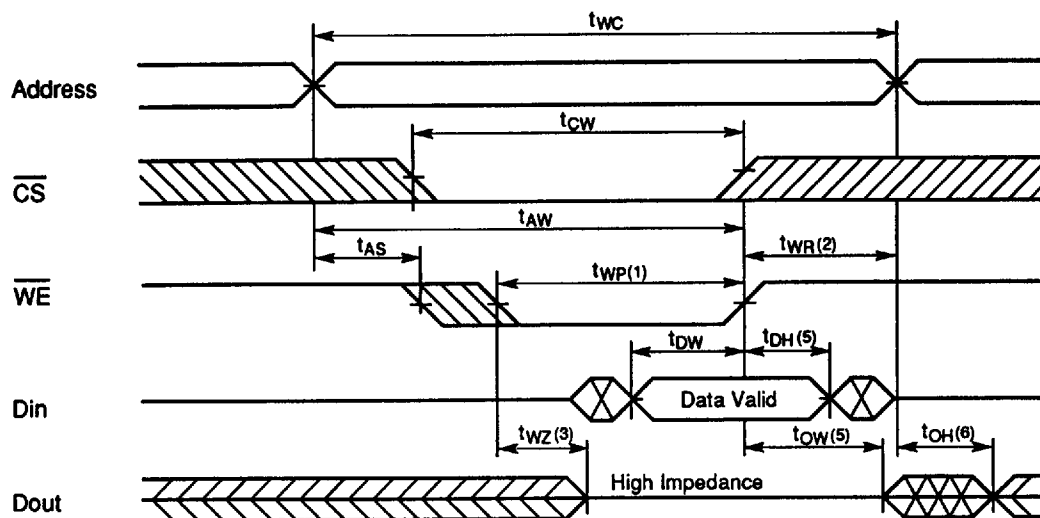
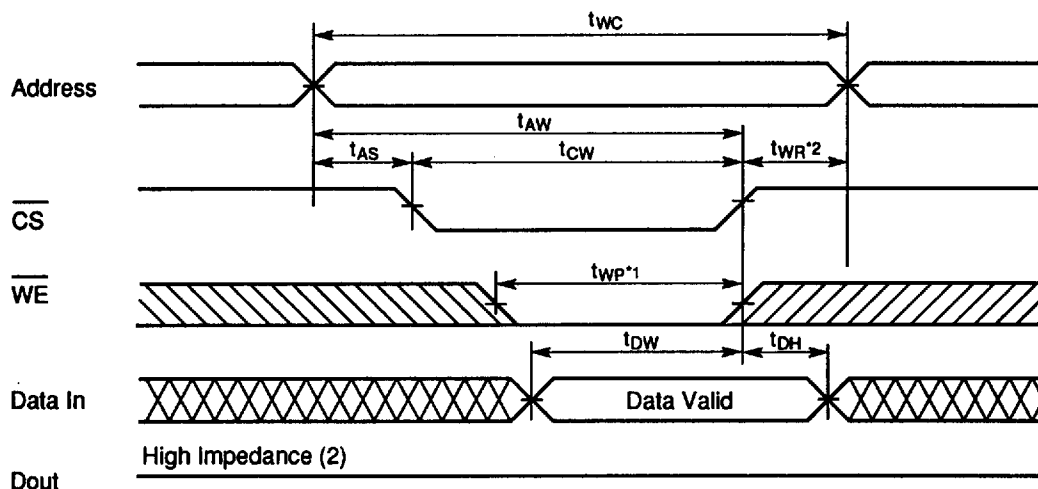


- NOTES:**
1. $\overline{WE}$ is High for READ cycle.
 2. Device is continuously selected, $\overline{CS} = V_{IL}$.
 3. Address valid prior to or coincident with $\overline{CS}$ transition low.



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• Write Cycle (1) ($\overline{WE}$ Controlled)

• Write Cycle (2) ($\overline{CS}$ Controlled)


NOTES:

1. A write occurs during the overlap of a low $\overline{CS}$ and a low $\overline{WE}$ (t_{wp}).
2. t_{wr} is measured from the earlier of $\overline{CS}$ or $\overline{WE}$ going high to the end of write cycle.
3. During this period, I/O pins are in the output state so that the input signals of opposite phase to the outputs must not be applied.
4. If the $\overline{CS}$ low transition occurs simultaneously with the $\overline{WE}$ low transition or after the $\overline{WE}$ transition, the output buffers remain in a high impedance state.
5. If $\overline{CS}$ is low during this period, I/O pins are in the output state. Then the data input signals of opposite phase to the outputs must not be applied to them.
6. Output data is the same phase of write data of this write cycle.

